

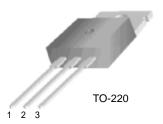
# FYP1004DN

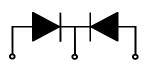
### **Features**

- · Low forward voltage drop
- High frequency properties and switching speed
- Guard ring for over-voltage protection

# **Applications**

- Switched mode power supply
- Freewheeling diodes





1. Anode 2. Cathode 3. Anode

## **SCHOTTKY BARRIER RECTIFIER**

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Maximum Repetitive Reverse Voltage	40	V
$V_R$	Maximum DC Reverse Voltage	40	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 137°C	10	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current (per diode) 60Hz Single Half-Sine Wave	80	А
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and Storage Temperature	-65 to +150	°C

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
R <sub>e.IC</sub>	Maximum Thermal Resistance, Junction to Case (per diode)	3.0	°C/W

## Electrical Characteristics (per diode)

Symbol	Parameter		Value	Units
V <sub>FM</sub> *	Maximum Instantaneous Forward Voltage $I_F = 5A$ $I_F = 5A$ $I_F = 10A$	$T_{C} = 25  ^{\circ}\text{C}$ $T_{C} = 125  ^{\circ}\text{C}$ $T_{C} = 25  ^{\circ}\text{C}$ $T_{C} = 125  ^{\circ}\text{C}$	0.55 0.49 0.67	V
	I <sub>F</sub> = 10A	T <sub>C</sub> = 125 °C	0.65	
I <sub>RM</sub> *	Maximum Instantaneous Reverse Current @ rated V <sub>R</sub>	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	1	mA
		T <sub>C</sub> = 125 °C	40	

<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

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# **Typical Characteristics**

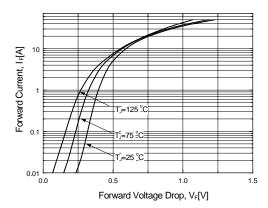


Figure 1. Typical Forward Voltage Characteristics (per diode)

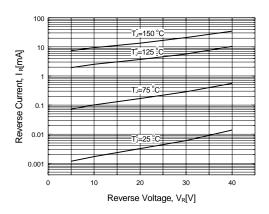


Figure 2. Typical Reverse Current vs. Reverse Voltage (per diode)

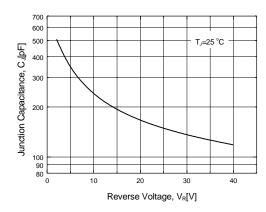


Figure 3. Typical Junction Capacitance (per diode)

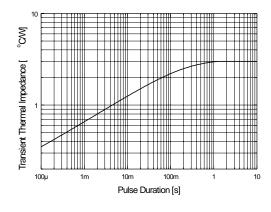


Figure 4. Thermal Impedance Characteristics (per diode)

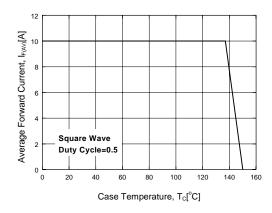


Figure 5. Forward Current Derating Curve

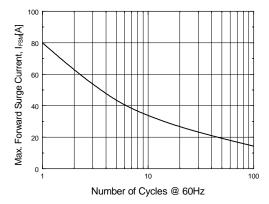


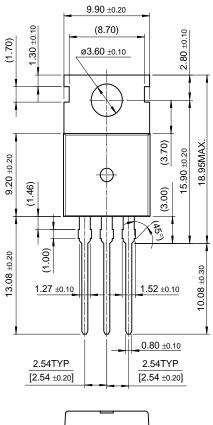
Figure 6. Non-Repetive Sureg Current (per diode)

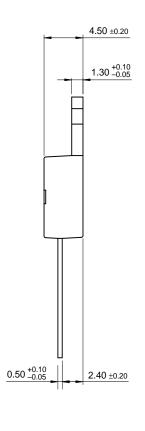
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# TO-220





10.00 ±0.20

Dimensions in Millimeters

Rev. A, March 2001

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EcoSPARK™	LittleFET™	Quiet Series™	UltraFET <sup>®</sup>
E <sup>2</sup> CMOS™	MicroFET™	SLIENT SWITCHER®	VCX™
EnSigna™	MICROWIRE™	SMART START™	
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